



Transient Voltage Suppressor

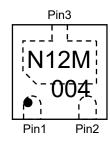
Description

The PTVSHC3N12VUHM transient voltage suppressor is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's.

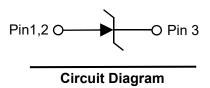
They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The PTVSHC3N12VUHM protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events.

The PTVSHC3N12VUHM is available in a DFN2020-3L package with working voltages of 12 volt.

It is used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (\pm 30kV air, \pm 30kV contact discharge)



Marking (Top View)



Feature

- \gt 5200W Peak pulse power per line (t_P = 8/20µs)
- ➤ DFN2020-3L package
- > Response time is typically < 1 ns
- > Protect one I/O or power line
- > RoHS compliant
- ➤ Transient protection for data lines to IEC 61000-4-2(ESD) ±30kV(air), 30kV(contact); IEC 61000-4-5 (Lightning) 220A (8/20us)

Applications

- > Power Management
- Industrial Application
- > Power Supply Protection
- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- > Portable instrumentation
- Cordless phones
- > Peripherals

Mechanical Characteristics

➤ Lead finish:100% matte Sn(Tin)

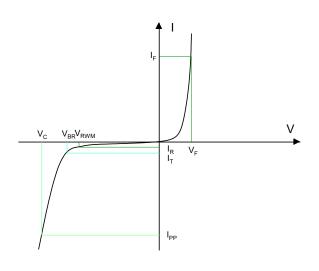
Mounting position: Any

Qualified max reflow temperature:260°C

➤ Pure tin plating: 7 ~ 17 um

Electronics Parameter

Symbol	Parameter			
V_{RWM}	Peak Reverse Working Voltage			
I _R	Reverse Leakage Current @ V _{RWM}			
V_{BR}	Breakdown Voltage @ I _T			
I _T	Test Current			
I _{PP}	Maximum Reverse Peak Pulse Current			
V _C	Clamping Voltage @ I _{PP}			
P _{PP}	Peak Pulse Power			
C _J	Junction Capacitance			
I _F	Forward Current			
V_{F}	Forward Voltage @ I _F			



Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}	-	-	-	12	V
Breakdown Voltage	V_{BR}	I _t = 1mA	13.5	-	16	V
Reverse Leakage Current	I _R	V _{RWM} = 12V	-	-	1.0	μA
Clamping Valtage	V _c	$I_{PP} = 140A, t_{P} = 8/20\mu s$	-	21	23	V
Clamping Voltage		$I_{PP} = 220A, t_{P} = 8/20\mu s$	-	23.5	27	V
Junction Capacitance	CJ	$V_R = 0V, f = 1MHz$	-	1600	1900	pF

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power (t _P = 8/20µs)	P _{PP}	5200	W
Peak Pulse Current (t _P = 8/20μs)	I _{PP}	220	Α
Lead Soldering Temperature	T _L	260 (10 sec)	°C
Junction and Storage Temperature Range	$T_{J_{I}}T_{STG}$	-55~+150	°C

Typical Characteristics

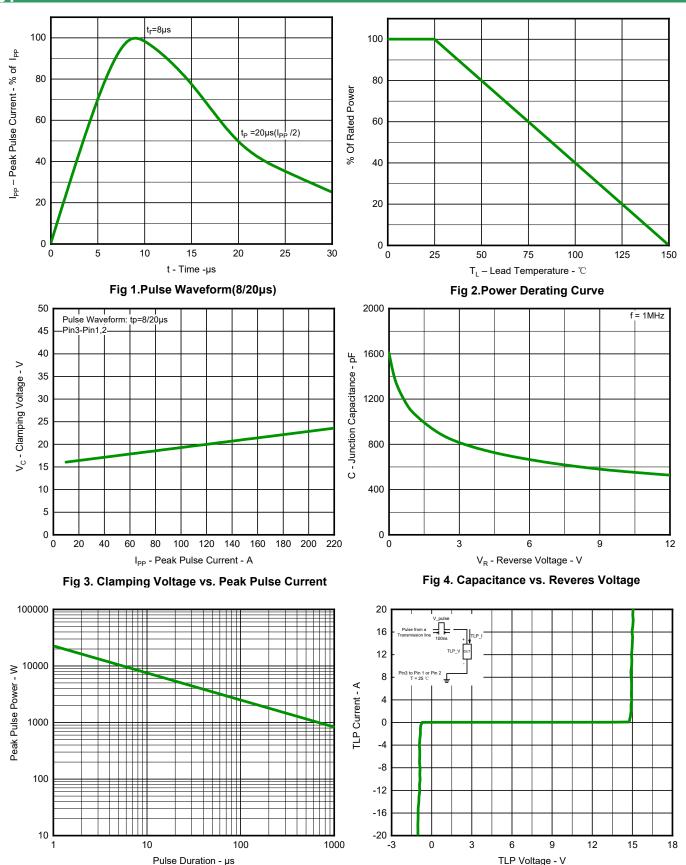
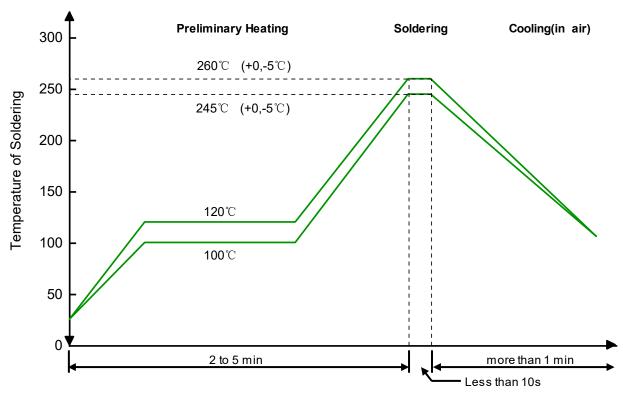


Fig 5. Non Repetitive Peak Pulse Power vs. Pulse Time

Fig 6. TLP Measurement

Solder Reflow Recommendation



Remark: Pb free for 260°C; Pb for 245°C.

PCB Design

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

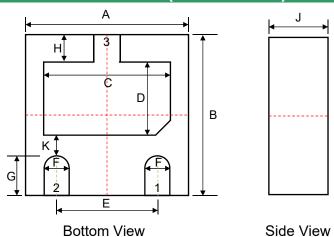
Ordering information

Device	Package	Reel	Shipping
PTVSHC3N12VUHM	DFN2020-3L (Pb-Free)	7"	3000 / Tape & Reel

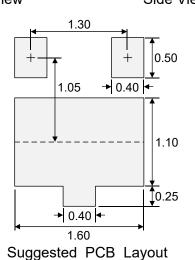
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PTVSHC3N12VUHM

Product dimension (DFN2020-3L)

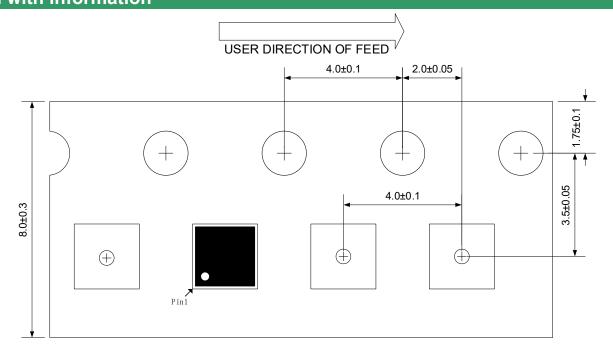


Dim	Millimeters		Inches		
	Min	Max	Min	Max	
Α	1.90	2.10	0.075	0.083	
В	1.90	2.10	0.075	0.083	
С	1.40	1.60	0.055	0.063	
D	0.90	1.15	0.035	0.045	
Е	1.30 BSC		0.051 BSC		
F	0.25	0.35	0.010	0.014	
G	0.35	0.45	0.014	0.018	
Н	0.15	0.30	0.006	0.012	
J	0.50	0.60	0.020	0.024	
K	0.30 BSC		0.012	BSC	



Unit:mm

Load with information



Unit:mm

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